

TRANSITION-MODE PFC CONTROLLER

Key Features

- REALISED IN BiCMOS TECHNOLOGY
- TRANSITION-MODE CONTROL OF PFC PREREGULATORS
- PROPRIETARY MULTIPLIER DESIGN FOR MINIMUM THD OF AC INPUT CURRENT
- VERY PRECISE ADJUSTABLE OUTPUT OVERVOLTAGE PROTECTION
- ULTRA-LOW ($\leq 50\mu\text{A}$) START-UP CURRENT
- LOW ($\leq 2.5\text{ mA}$) QUIESCENT CURRENT
- EXTENDED IC SUPPLY VOLTAGE RANGE
- ON-CHIP FILTER ON CURRENT SENSE
- DISABLE FUNCTION
- 1% (@ $T_j = 25\text{ }^\circ\text{C}$) INTERNAL REFERENCE VOLTAGE
- -600/+800mA TOTEM POLE GATE DRIVER WITH UVLO PULL-DOWN AND VOLTAGE CLAMP
- DIP-8/SO-8 PACKAGES

Applications

- PFC PRE-REGULATORS FOR:
- IEC61000-3-2 COMPLIANT SMPS (TV, DESKTOP PC, MONITOR) UP TO 300W
- HI-END AC-DC ADAPTER/CHARGER
- ENTRY LEVEL SERVER & WEB SERVER

Figure 1. Packages



DIP-8



SO-8

General Description

The IMP6562 is a current-mode PFC controller operating in Transition Mode (TM). Pin-to-pin compatible

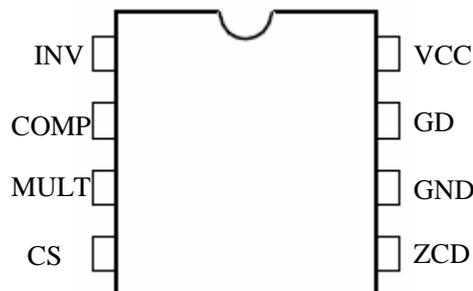
with the L6562, it offers improved performance.

The highly linear multiplier includes a special circuit, able to reduce AC input current distortion, that allows wide-range-mains operation with an extremely low THD, even over a large load range.

The output voltage is controlled by means of a voltage-mode error amplifier and a precise (1% @ $T_j = 25^\circ\text{C}$) internal voltage reference.

The device features extremely low consumption ($\leq 40\mu\text{A}$ before start-up and $< 2\text{mA}$ running) and includes a

Figure 2. Pin Connection (Top view)



TRANSITION-MODE PFC CONTROLLER

General Description

(Continued)

which makes it easier to comply with energy saving norms (Blue Angel, EnergyStar, Energy2000, etc.). An effective two-step OVP enables to safely handle overvoltages either occurring at start-up or resulting from load disconnection.

The totem-pole output stage, capable of 600 mA source and 800 mA sink current, is suitable for big MOSFET or IGBT drive which, combined with the other features, makes the device an excellent low-cost solution for EN61000-3-2 compliant SMPS's up to 300W.

Table 1. Pin Description

N°	Pin	Function
1	INV	Inverting input of the error amplifier. The information on the output voltage of the PFC pre-regulator is fed into the pin through a resistor divider.
2	COMP	Output of the error amplifier. A compensation network is placed between this pin and INV (pin #1) to achieve stability of the voltage control loop and ensure high power factor and low THD.
3	MULT	Main input to the multiplier. This pin is connected to the rectified mains voltage via a resistor divider and provides the sinusoidal reference to the current loop.
4	CS	Input to the PWM comparator. The current flowing in the MOSFET is sensed through a resistor, the resulting voltage is applied to this pin and compared with an internal sinusoidal-shaped reference, generated by the multiplier, to determine MOSFET's turn-off.
5	ZCD	Boost inductor's demagnetization sensing input for transition-mode operation. A negative-going edge triggers MOSFET's turn-on.
6	GND	Ground. Current return for both the signal part of the IC and the gate driver.
7	GD	Gate driver output. The totem pole output stage is able to drive power MOSFET's and IGBT's with a peak current of 600 mA source and 800 mA sink. The high-level voltage of this pin is clamped at about 12V to avoid excessive gate voltages in case the pin is supplied with a high Vcc.
8	Vcc	Supply Voltage of both the signal part of the IC and the gate driver. The supply voltage upper limit is extended to 22V min. to provide more headroom for supply voltage changes.

Table 2. Thermal Data

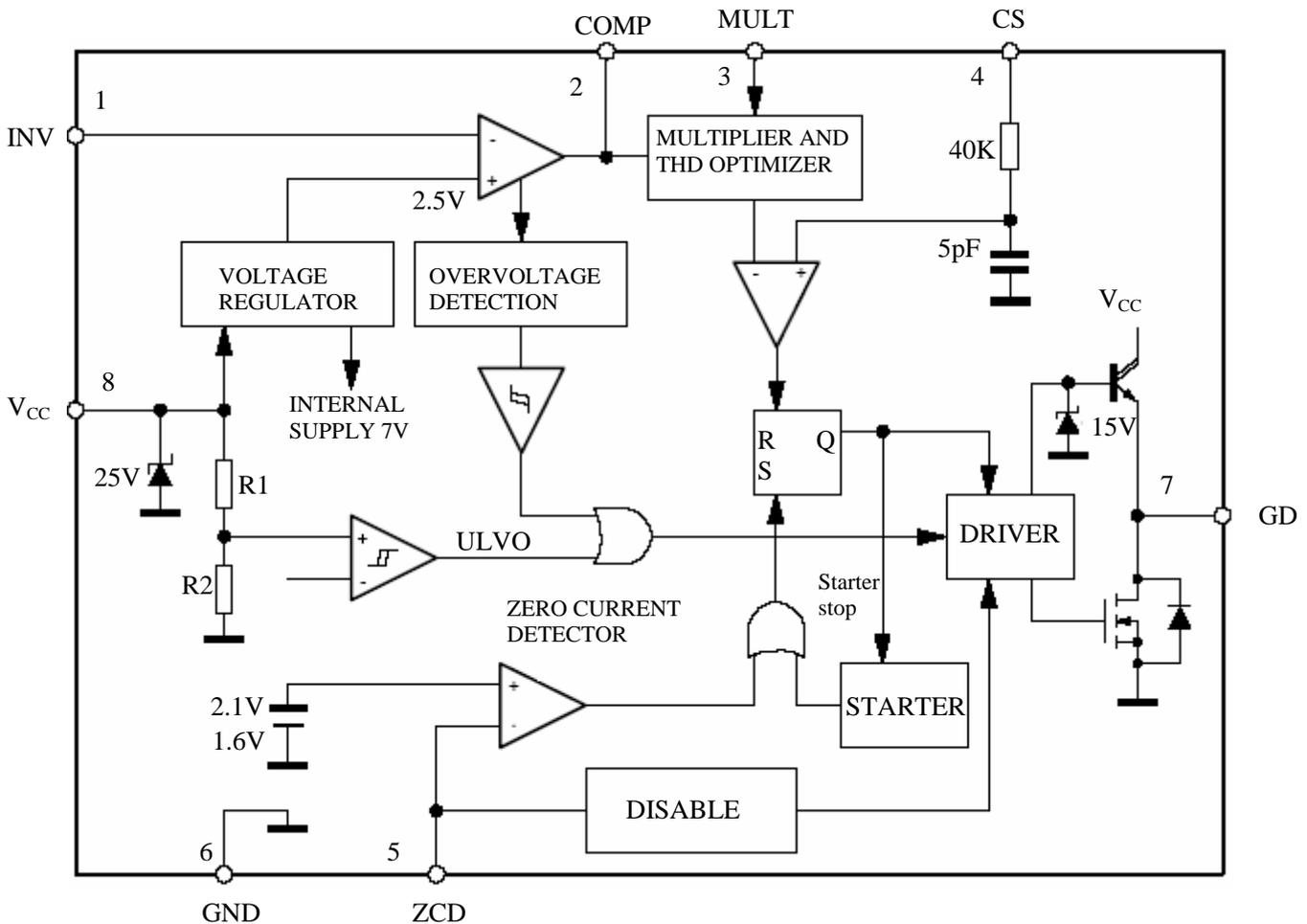
Symbol	Parameter	SO8	Minidip	Unit
$R_{th\ j-amb}$	Max. Thermal Resistance, Junction-to-ambient	150	100	°C/W

TRANSITION-MODE PFC CONTROLLER

Table 3. Absolute Maximum Ratings

Symbol	Pin	Parameter	Value	Unit
VCC	8	IC Supply voltage ($I_{cc} = 20 \text{ mA}$)	self-limited	V
IGD	7	Output Totem Pole Peak Current	± 0.8	A
---	1 to 4	Analog Inputs & Outputs	-0.3 to 6	V
IZCD	5	Zero Current Detector Max. Current	-10 (source) 10 (sink)	mA
Ptot		Power Dissipation @ $T_{amb} = 50^\circ\text{C}$ (DIP-8) (SO-8)	1 0.65	W
Tj		Junction Temperature Operating range	-40 to 125	$^\circ\text{C}$
Tstg		Storage Temperature	-55 to 150	$^\circ\text{C}$

Figure 3. Block Diagram



TRANSITION-MODE PFC CONTROLLER

Table 4. Electrical Characteristic

($T_j = -25$ to 125°C , $V_{CC} = 13$, $C_O = 1$ nF; unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
SUPPLY VOLTAGE						
V_{CC}	Operating range	After turn-on	10.3		22	V
V_{CCon}	Turn-on threshold	(1)	11.5	12.5	13.5	V
V_{CCoff}	Turn-off threshold	(1)	9	10	10.5	V
H_{ys}	Hysteresis		2.2		2.8	V
V_Z	Zener Voltage	$I_{CC} = 20$ mA	22	25	27	V
SUPPLY CURRENT						
$I_{start-up}$	Start-up Current	Before turn-on, $V_{CC} = 11$ V		30	50	μA
I_q	Quiescent Current	After turn-on		1.7	2.5	mA
I_{CC}	Operating Supply Current	@ 70 kHz		3.5	5	mA
I_q	Quiescent Current	During OVP (either static or dynamic) or $V_{ZCD} = 150$ mV			2.2	mA
MULTIPLIER INPUT						
I_{MULT}	Input Bias Current	$V_{VFF} = 0$ to 4 V			-1	μA
V_{MULT}	Linear Operation Range		0 to 3			V
$\frac{DV_{CS}}{DV_{MULT}}$	Output Max. Slope	$V_{MULT} = 0$ to 0.5V $V_{COMP} =$ Upper clamp	1.65	1.9		V/V
K	Gain (2)	$V_{MULT} = 1$ V, $V_{COMP} = 4$ V	0.5	0.6	0.7	1/V
ERROR AMPLIFIER						
V_{INV}	Voltage Feedback Input Threshold	$T_j = 25^\circ\text{C}$	2.465	2.5	2.535	V
		$10.3\text{ V} < V_{CC} < 22\text{ V}$ (1)	2.44		2.56	
	Line Regulation	$V_{CC} = 10.3\text{ V}$ to 22V		2	5	mV
I_{INV}	Input Bias Current	$V_{INV} = 0$ to 3 V			-1	μA
G_v	Voltage Gain	Open loop	60	80		dB
G_B	Gain-Bandwidth Product			1		MHz
I_{COMP}	Source Current	$V_{COMP} = 4$ V, $V_{INV} = 2.4$ V	-2	-2.5	-5	mA
I_{COMP}	Sink Current	$V_{COMP} = 4$ V, $V_{INV} = 2.6$ V	5	8.5		mA
V_{COMP}	Upper Clamp Voltage	$I_{SOURCE} = 0.5$ mA	4	4.5	5	V
V_{COMP}	Lower Clamp Voltage	$I_{SINK} = 0.5$ mA (1)	2.1	2.25	2.4	V

TRANSITION-MODE PFC CONTROLLER

Table 4. Electrical Characteristic

(Continued)

($T_j = -25$ to 125°C , $V_{CC} = 13$, $C_O = 1$ nF; unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
CURRENT SENSE COMPARATOR						
I_{CS}	Input Bias Current	$V_{CS} = 0$			-1	μA
$t_{d(H-L)}$	Delay to Output			200	350	ns
$V_{CS\ clamp}$	Current sense reference clamp	$V_{COMP} = \text{Upper clamp}$	1.6	1.7	1.8	V
$V_{CS\ offset}$	Current sense offset	$V_{MULT} = 0$		50		mV
		$V_{MULT} = 2.5\text{V}$		15		
ZERO CURRENT DETECTOR						
V_{ZCDH}	Upper Clamp Voltage	$I_{ZCD} = 2.5\ \text{mA}$	5.4	5.7	6.2	V
V_{ZCDL}	Lower Clamp Voltage	$I_{ZCD} = -2.5\ \text{mA}$	0.3	0.65	1	V
V_{ZCDA}	Arming Voltage (positive-going edge)	(3)		2.1		V
V_{ZCDT}	Triggering Voltage (negative-going edge)	(3)		1.5		V
I_{ZCDb}	Input Bias Current	$V_{ZCD} = 1$ to $4.5\ \text{V}$		2		μA
I_{ZCDsrc}	Source Current Capability		-2.5			mA
I_{ZCDsnk}	Sink Current Capability		2.5			mA
V_{ZCDdis}	Disable threshold		150	200	250	mV
V_{ZCDen}	Restart threshold				350	mV
I_{ZCDres}	Restart Current after Disable		30	85		μA
STARTER						
t_{START}	Start Timer period		75	130	300	μs
OUTPUT OVERVOLTAGE						
I_{OVP}	Dynamic OVP triggering current		35	40	45	μA
H_{ys}	Hysteresis	(3)		30		μA
	Static OVP threshold	(1)	2.1	2.25	2.4	V
GATE DRIVER						
V_{OH}	Dropout Voltage	$I_{GDsource} = 20\ \text{mA}$		2	2.6	
		$I_{GDsource} = 200\ \text{mA}$		2.5	3	V
V_{OL}		$I_{GDsink} = 200\ \text{mA}$		0.9	1.9	V
t_f	Voltage Fall Time			30	70	ns
t_r	Voltage Rise Time			40	80	ns
V_{Oclamp}	Output clamp voltage	$I_{GDsource} = 5\ \text{mA}$; $V_{cc} = 20\ \text{V}$	10	12	15	V
	UVLO saturation	$V_{CC} = 0$ to V_{CCON} , $I_{sink} = 10\ \text{mA}$			1.1	V

(1) All parameters are in tracking

(2) The multiplier output is given by: $V_{CS} = K * V_{MULT} * (V_{COMP} - 2.5)$

(3) Parameters guaranteed by design, functionality tested in production.

TRANSITION-MODE PFC CONTROLLER

APPLICATION INFORMATION

Overvoltage protection

Under steady-state conditions, the voltage control loop keeps the output voltage V_o of a PFC pre-regulator close to its nominal value, set by the resistors R_1 and R_2 of the output divider. Neglecting ripple components, the current through R_1 , I_{R1} , equals that through R_2 , I_{R2} . Considering that the non-inverting input of the error amplifier is internally referenced at 2.5V, also the voltage at pin INV will be 2.5V, then:

$$I_{R2} = \frac{2.5}{R_2} = I_{R1} = \frac{V_o - 2.5}{R_1}$$

If the output voltage experiences an abrupt change $\Delta V_o > 0$ due to a load drop, the voltage at pin INV will be kept at 2.5V by the local feedback of the error amplifier, a network connected between pins INV and COMP that introduces a long time constant to achieve high PF (this is why ΔV_o can be large). As a result, the current through R_2 will remain equal to $2.5/R_2$ but that through R_1 will become:

$$I_{R1} = \frac{V_o - 2.5 + \Delta V_o}{R_1}$$

The difference current $\Delta I_{R1} = I'_{R1} - I_{R2} = I'_{R1} - I_{R1} = \Delta V_o / R_1$ will flow through the compensation network and enter the error amplifier output (pin COMP). This current is monitored inside the IMP6562 and if it reaches about 37 μA the output voltage of the multiplier is forced to decrease, thus smoothly reducing the energy delivered to the output. As the current exceeds 40 μA , the OVP is triggered (Dynamic OVP): the gate-drive is forced low to switch off the external power transistor and the IC put in an idle state. This condition is maintained until the current falls below approximately 10 μA , which re-enables the internal starter and allows switching to restart. The output ΔV_o that is able to trigger the Dynamic OVP function is then:

$$\Delta V_o = R_1 \times 40 \times 10^{-6}$$

An important advantage of this technique is that the OV level can be set independently of the regulated output voltage: the latter depends on the ratio of R_1 to R_2 , the former on the individual value of R_1 . Another advantage is the precision: the tolerance of the detection current is 12%, that is 12% tolerance on ΔV_o . Since $\Delta V_o \ll V_o$, the tolerance on the absolute value will be proportionally reduced.

Example: $V_o = 400$ V, $\Delta V_o = 40$ V. Then: $R_1 = 40V / 40\mu A = 1M\Omega$; $R_2 = 1M\Omega \cdot 2.5 / (400 - 2.5) = 6.289k\Omega$. The tolerance on the OVP level due to the IMP6562 will be $40 \cdot 0.12 = 4.8V$, that is 1.2% of the regulated value.

TRANSITION-MODE PFC CONTROLLER

APPLICATION INFORMATION

(Continued)

When the load of a PFC pre-regulator is very low, the output voltage tends to stay steadily above the nominal value, which cannot be handled by the Dynamic OVP. If this occurs, however, the error amplifier output will saturate low; hence, when this is detected, the external power transistor is switched off and the IC put in an idle state (Static OVP). Normal operation is resumed as the error amplifier goes back into its linear region. As a result, the IMP6562 will work in burst-mode, with a repetition rate that can be very low.

When either OVP is activated the quiescent consumption of the IC is reduced to minimize the discharge of the Vcc capacitor and increase the hold-up capability of the IC supply system.

THD optimizer circuit

The IMP6562 is equipped with a special circuit that reduces the conduction dead-angle occurring to the AC input current near the zero-crossings of the line voltage (crossover distortion). In this way the THD (Total Harmonic Distortion) of the current is considerably reduced.

A major cause of this distortion is the inability of the system to transfer energy effectively when the instantaneous line voltage is very low. This effect is magnified by the high-frequency filter capacitor placed after the bridge rectifier, which retains some residual voltage that causes the diodes of the bridge rectifier to be reverse-biased and the input current flow to temporarily stop.

To overcome this issue the circuit embedded in the IMP6562 forces the PFC pre-regulator to process more energy near the line voltage zero-crossings as compared to that commanded by the control loop. This will result in both minimizing the time interval where energy transfer is lacking and fully discharging the highfrequency filter capacitor after the bridge. The effect of the circuit is shown in figure 4, where the key waveforms of a standard TM PFC controller are compared to those of the IMP6562.

Essentially, the circuit artificially increases the ON-time of the power switch with a positive offset added to the output of the multiplier in the proximity of the line voltage zero-crossings. This offset is reduced as the instantaneous line voltage increases, so that it becomes negligible as the line voltage moves toward the top of the sinusoid.

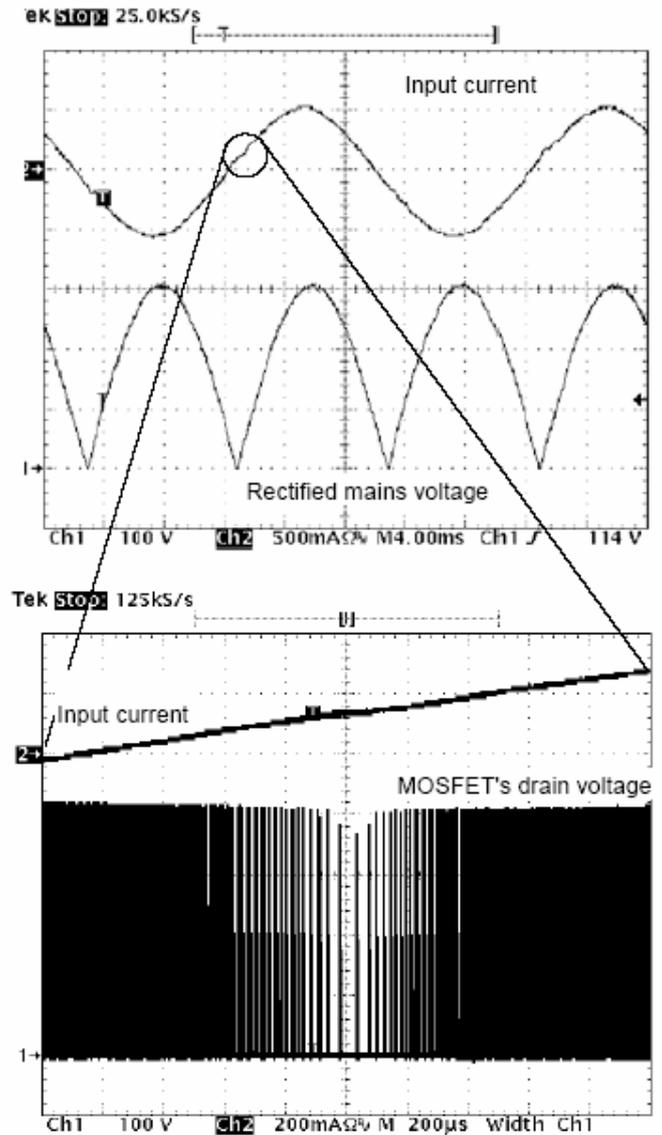
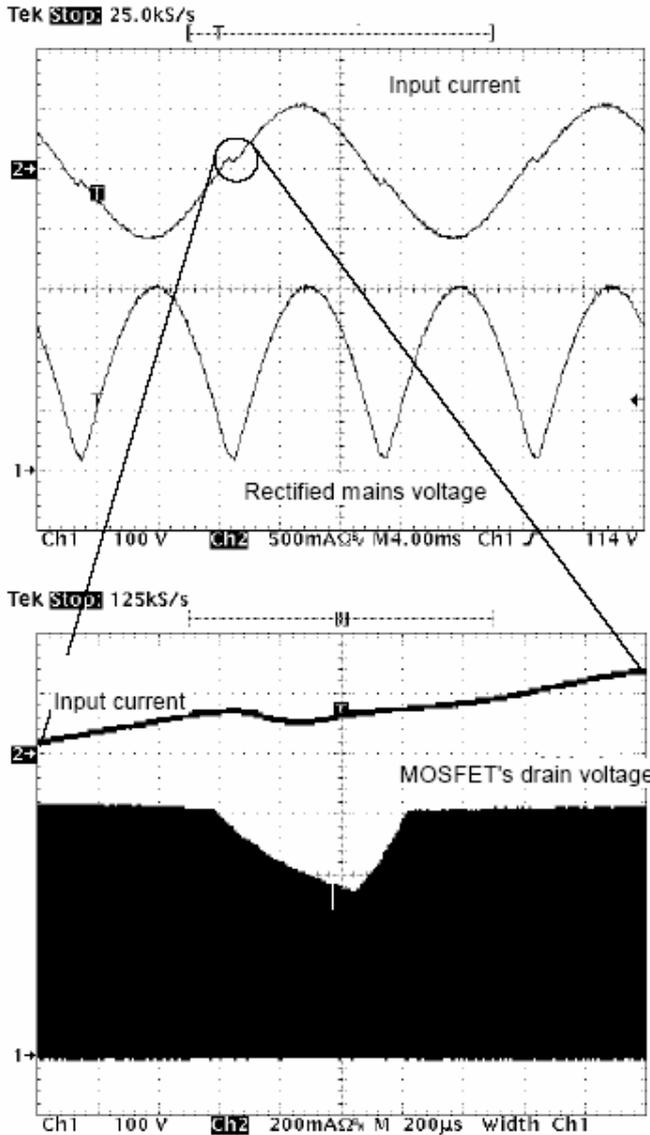
To maximally benefit from the THD optimizer circuit, the high-frequency filter capacitor after the bridge rectifier should be minimized, compatibly with EMI filtering needs. A large capacitance, in fact, introduces a conduction dead-angle of the AC input current in itself - even with an ideal energy transfer by the PFC preregulator - thus making the action of the optimizer circuit little effective.

TRANSITION-MODE PFC CONTROLLER

APPLICATION INFORMATION

(Continued)

Figure 4. THD optimization: standard TM PFC controller (left side) and IMP6562 (right side)



TRANSITION-MODE PFC CONTROLLER

APPLICATION INFORMATION

(Continued)

Figure 5. Typical application circuit (250W, Wide-range mains)

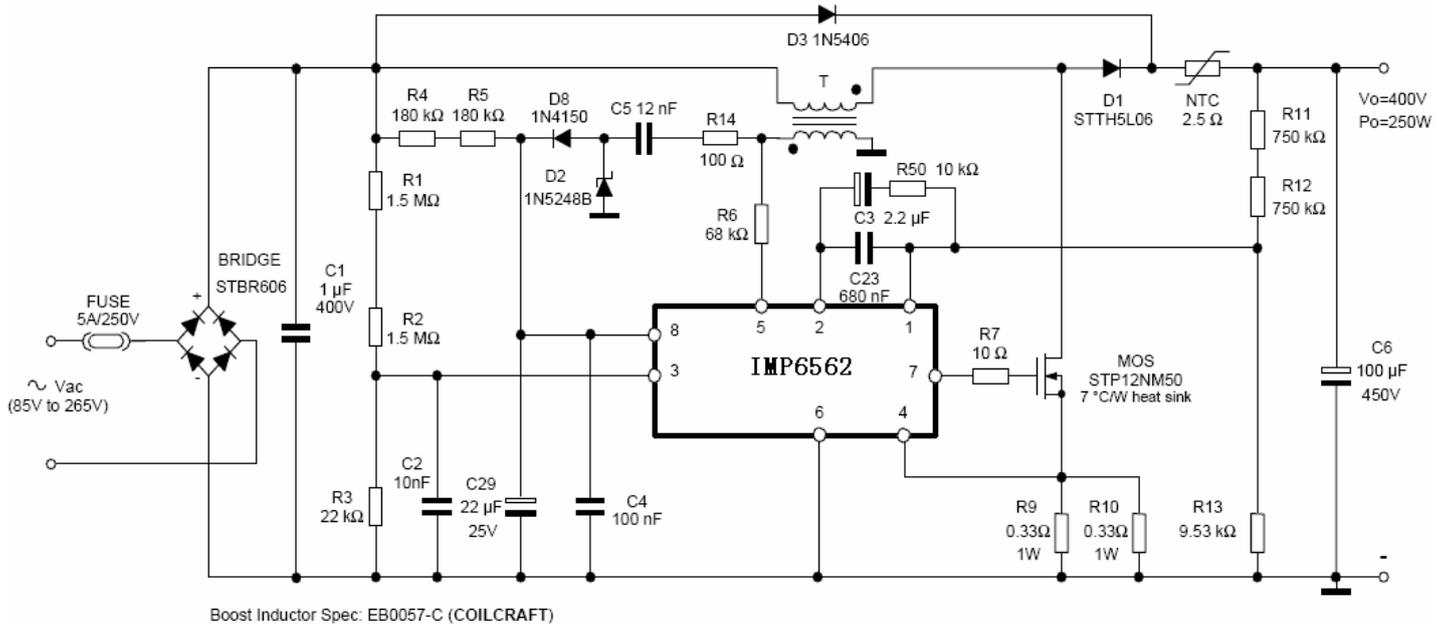
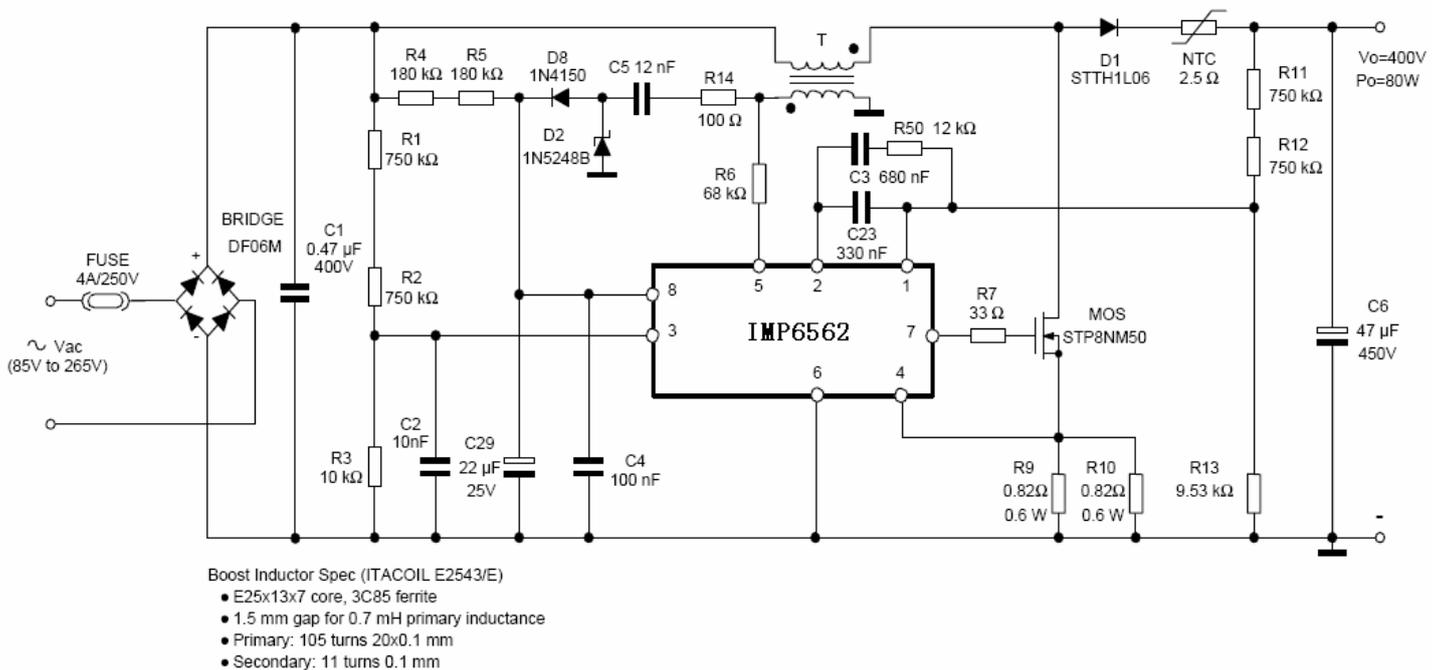


Figure 6. Demo board (IMP6562-80W, Wide-range mains): Electrical schematic



TRANSITION-MODE PFC CONTROLLER

APPLICATION INFORMATION

(Continued)

Figure 7. IMP6562-80W: PCB and component layout (Top view, real size: 57 x 108 mm)

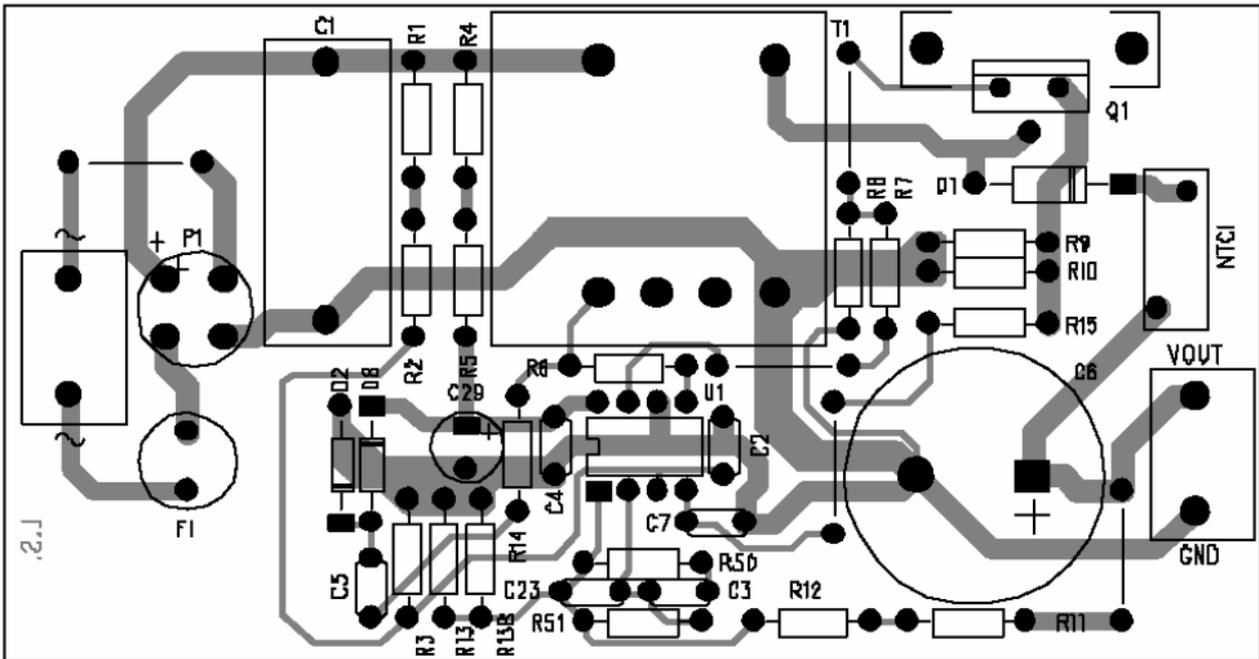


Table 5. IMP6562: Evaluation results at full load

Vin (VAC)	Pin (W)	Vo (VDC)	ΔV_o (Vpk-pk)	Po (W)	η (%)	PF	THD (%)
85	86.4	394.79	12.8	80.16	92.8	0.998	3.6
110	84.6	394.86	12.8	80.20	94.8	0.996	4.2
135	83.8	394.86	12.8	80.20	95.7	0.991	4.9
175	83.2	394.87	15.5	80.20	96.4	0.981	6.5
220	82.9	394.87	15.7	80.20	96.7	0.956	7.8
265	82.7	394.87	15.9	80.20	97.0	0.915	9.2

Note: measurements done with the line filter shown in figure 5

TRANSITION-MODE PFC CONTROLLER

APPLICATION INFORMATION

(Continued)

Table 6. IMP6562: Evaluation results at half load

Vin (VAC)	Pin (W)	Vo (VDC)	$\Delta V_o(V_{pk-pk})$	Po (W)	$\eta(\%)$	PF	THD (%)
85	42.8	394.86	6.6	40.20	93.9	0.994	5.5
110	42.5	394.90	6.6	40.20	94.6	0.985	6.2
135	42.5	394.91	6.7	40.20	94.6	0.967	7.1
175	42.5	394.93	8.0	40.19	94.6	0.939	8.3
220	42.6	394.94	8.2	40.19	94.3	0.869	9.8
265	42.6	394.94	8.3	40.19	94.3	0.776	11.4

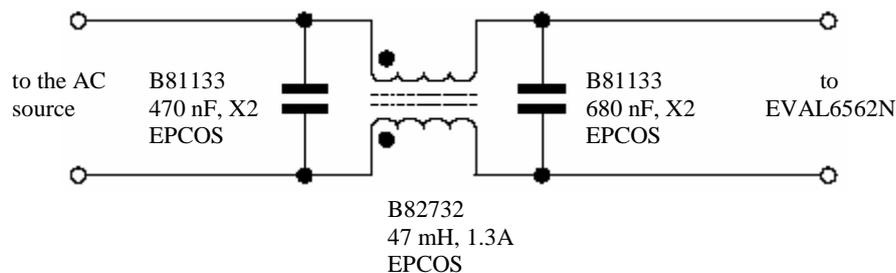
Note: measurements done with the line filter shown in figure 5

Table 7. IMP6562: No-load measurements

Vin (VAC)	Pin (W)	Vo (VDC)	DVo(Vpk-pk)	Po (W)
85	0.4	396.77	0.45	0
110	0.3	396.82	0.55	0
135	0.3	396.83	0.60	0
175 (*)	0.4	396.90	1.00	0
220 (*)	0.4	396.95	1.40	0
265 (*)	0.5	396.98	1.65	0

(*) $V_{cc} = 12V$ supplied externally

Figure 8. Line filter (not tested for EMI compliance) used for IMP6562 evaluation



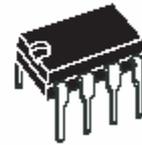
TRANSITION-MODE PFC CONTROLLER

Mechanical Dimensions

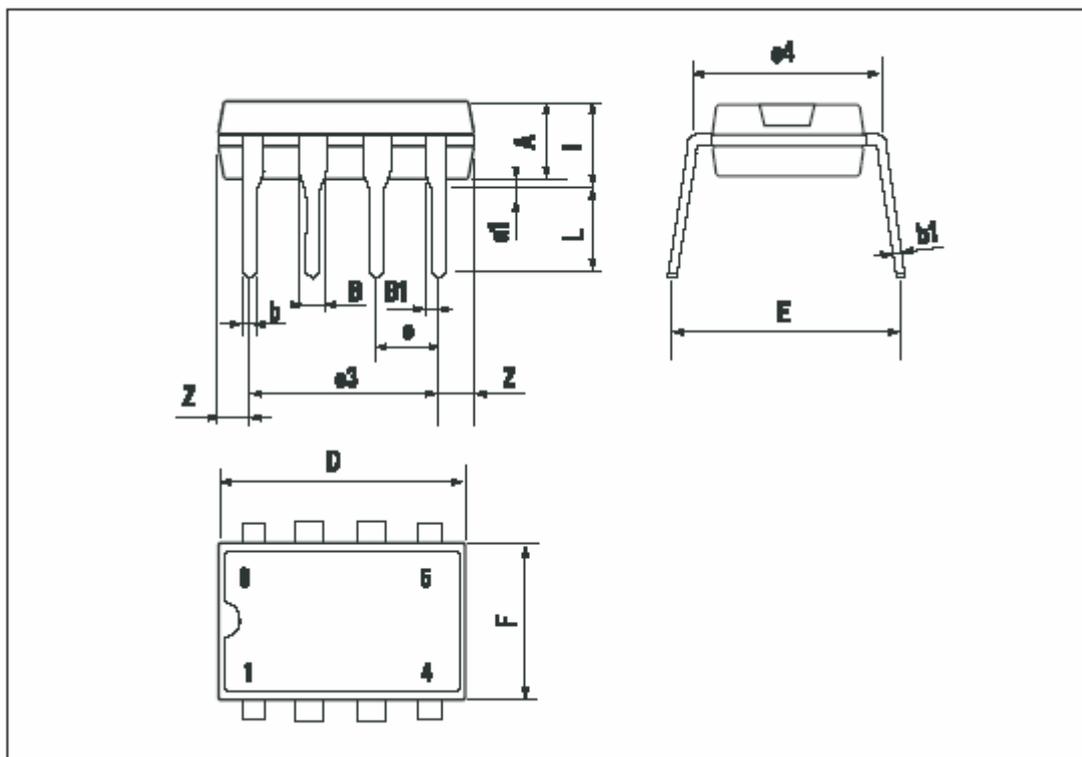
Figure 9. DIP-8 Mechanical Data & Package Dimensions

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
I			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

OUTLINE AND MECHANICAL DATA



DIP-8



TRANSITION-MODE PFC CONTROLLER

Mechanical Dimensions

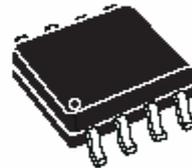
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Figure 10. SO-8 Mechanical Data & Package Dimensions

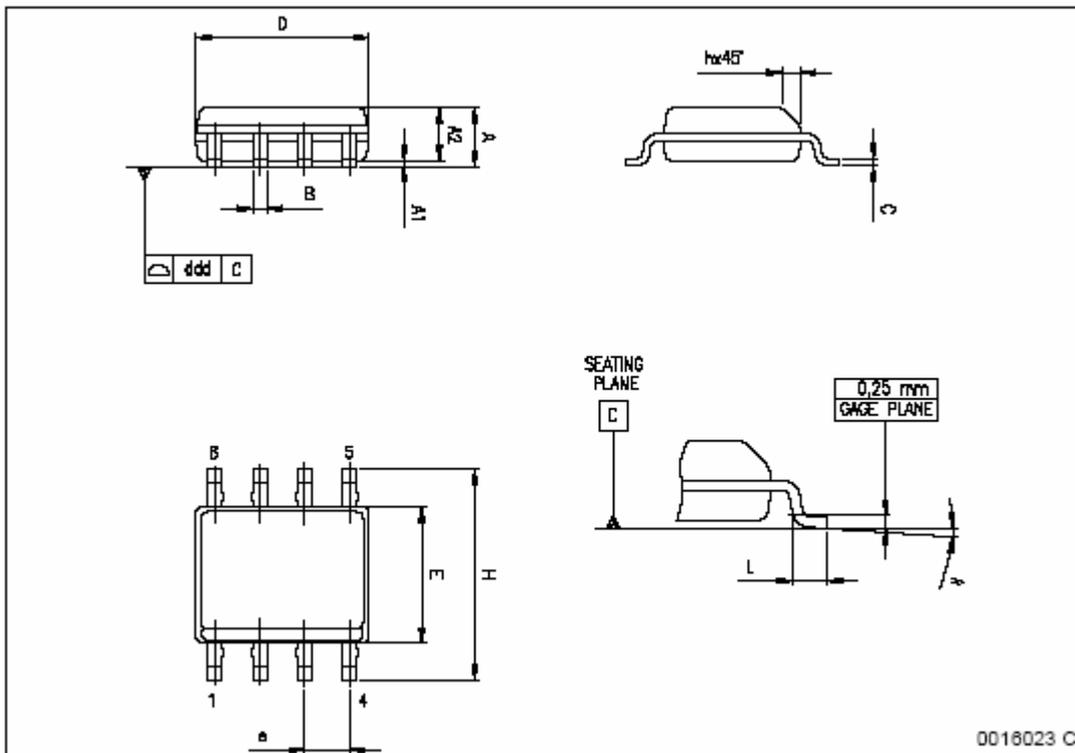
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
B	0.33		0.51	0.013		0.020
C	0.19		0.25	0.007		0.010
D ⁽¹⁾	4.80		5.00	0.189		0.197
E	3.80		4.00	0.15		0.157
e		1.27			0.050	
H	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	0° (min.), 8° (max.)					
ddd			0.10			0.004

Note: (1) Dimensions D does not include mold flash, protrusions or gate burrs.
Mold flash, protrusions or gate burrs shall not exceed 0.15mm (.006inch) in total (both side).

OUTLINE AND MECHANICAL DATA



SO-8



TRANSITION-MODE PFC CONTROLLER

Ordering Information

Part Number	Package
IMP6562EPA	DIP-8
IMP6562ESA	SO-8



ISO 9001 Registered

Daily Silver IMP Microelectronics Co.,Ltd
7 keda Road ,Hi-Tech Park,
NingBo,Zhejiang,P.R.C
Post Code:315040
Tel:(086)-574-87906358
Fax:(086)-574-87908866
Email:sales@ds-imp.com.cn
<http://www.ds-imp.com.cn>

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